## TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT Docket No. (Under 37 CFR 1.97(b) or 1.97(c)) 50033-00006 In Re Application Of: VAN ZEGHBROECK et al Serial No. Filing Date Examiner Group Art Unit 10/630,238 July 30, 2003 Not Yet Assigned 1765 Title: "WIDE BANDGAP SEMICONDUCTOR DEVICE CONSTRUCTION" Address to: **Commissioner for Patents** NOV 0 7 2003 P.O. Box 1450 Alexandria, VA 22313-1450 37 CFR 1.97(b) The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114. 37 CFR 1.97(c) 2. The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of: ☐ the statement specified in 37 CFR 1.97(e); OR $\Box$ the fee set forth in 37 CFR 1.17(p).

## TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT Docket No. (Under 37 CFR 1.97(b) or 1.97(c)) 50033-00006 In Re Application: VAN ZEGHBROECK et al Serial No. Filing Date Examiner **Group Art Unit** 10/630,238 July 30, 2003 Not Yet Assigned 1765 "WIDE BANDGAP SEMICONDUCTOR DEVICE CONSTRUCTION" NOV 0 7 2003 Payment of Fee (Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p)) is attached. ☑ The Director is hereby authorized to charge and credit Deposit Account 50-1419 as described below. Charge the amount of Credit any overpayment. Charge any additional fee required. Certificate of Transmission by Facsimile\* Certificate of Mailing by First Class Mail I certify that this document and authorization to charge deposit I certify that this document and fee is being deposited account is being facsimile transmitted to the United States on November 5, 2003 with the U.S. Postal Service Patent and Trademark Office (Fa as first class mail under 37 C.F.R. 1.8 and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450. (Date) Signature of Person Mailing Correspondence Signature Bobbye D. Simon Typed or Printed Name of Person Signing Certificate Typed or Printed Name of Person Mailing Certificate \*This certificate may only be used if paying by deposit agcount. Dated: November 5, 2003 Travis C. Stephenson, Esq. Registration No. 45,132 MARSH FISCHMANN & BREYFOGLE LLP 3151 South Vaughn Way, Suite 411 Aurora, Colorado 80014 (720)562-5500 cc:

## PATENT APPLICATION

## IN THE TARRED STATES PATENT AND TRADEMARK OFFICE

In Re the Applicati	lon	ot:
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VAN ZEGHBROECK et al

Serial No.:

Filed: July 30, 2003

Confirmation No.:

Atty. File No.: 50033-00006

For: "WIDE BANDGAP

SEMICONDUCTOR DEVICE

CONSTRUCTION"

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

OF GROUP Art Unit: 1765

Examiner: Not Yet Assigned

INFORMATION DISCLOSURE STATEMENT

CERTIFICATE OF MAILING

I HEREBY CERTIFY THAT THIS CORRESPONDENCE IS BEING DEPOSITED WITH THE UNITED STATES POSTAL SERVICE AS FIRST CLASS MAIL IN AN ENVELOPE ADDRESSED TO COMMISSIONER FOR PATENTS, P.O. BOX 1450, ALEXANDRIA, VA 22313-1430 ON November 5, 2003

MARSH HISCHMANN & BREYFOGLE LLP

BY: Bobbye D. Sippoi

Pursuant to Applicant's duty of disclosure under 37 CFR § 1.56 and 37 CFR §§ 1.97-1.98, Applicant hereby provides a copy of each of the documents identified on the enclosed PTO Form 1449, although Applicant does not admit that any of such documents, alone or in any combination, is considered to be material to patentability as defined in 37 CFR § 1.56(b). Moreover, the inclusion of these documents is not to be construed as an admission by Applicant that each such document is prior art as to the above-identified application.

Respectfully submitted,

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By:

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Date: November 5, 2003

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	Nov				7 2003	HILING DATE July 30, 2003		GROUP 1765			
	-			ATEN U.S	S. PATENT	DOCUMENTS					
*EXAMINER			DOCUMENT NUMBER	DATE	NAME		CLASS	SUBCLASS	FILING DATE IF APPROPRIATE		
	a.	H16	537	03/04/1997	Offord	et al	437	173			
	b.	4,94	15,394	07/31/1990	Palmou	ır et al	357	34			
	c.	5,26	66,503	11/30/1993	Wang e	et al	437	24			
	d.	6,18	80,958	01/30/2001	Cooper	, Jr.	257	77			
	e.	6,18	81,200	01/30/2001	Titiziar	n et al	330	66			
_	f.	6,30	03,475	10/16/2001	Suvoro	v et al	438	519			
	g.	6,31	13,482	11/06/2001	Baliga		257	77			
	h.	6,32	23,506	11/27/2001	Alok		257	77			
	i.	6,32	29,675	12/11/2001	Singh et al		257	77			
	j.	6,33	31,931	12/18/2001	Titiziar	n et al	361	306.3			
	k.	6,218,254		04/17/2001	Singh et al		438	364			
				FORE	IGN PATE	ENT DOCUMENTS					
			DOCUMENT NUMBER	DATE	COUNTRY		CLASS	SUBCLASS	TRANSLATION YES NO		
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	1	1	OTHER DOCUME	NTS (Includir	ng Autho	r, Title, Date, Pertinent	Pages, Etc.	)	1	l	
		Article entitled "Silicon Carbide Bipolar Transistor" by W. V. Munch and P. Hoeck published in Solid State Electronics, 1978, Vol. 21, pp. 479-480, Pergamon Press, Great Britain									
		m.	Excerpt from textbook Volume V Introduction to Microelectronic Fabrication, pp. 71-73, author Richard C. Jaeger, Auburn University, published by Addison-Wesley Publishing Company, reprinted with corrections May, 1993.								
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					July 30, 2003		1765			
•		_	MADENAS	S.S. PAT	ENT DOCUMENTS					
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE		NAME	CLASS	SUBCLASS	ì	FILING DATE  IF APPROPRIATE	
	n.	5,914,611	06/22/1999	Cheng		324 719				
	0.	6,228,665	05/08/2001	Griffith	et al	438	14			
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	REF	DOCUMENT NUMBER	DATE		COUNTRY	CLASS	SUBCLASS	Trans YES	lation NO	
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				OTHER	DOCUMENTS (Including A	Author, Title, D	ate, Pertinent Pa	ges, Etc.)		
	]	U. S. Patent Application Silicon Carbide Semicon	n Serial No. 10/30 nductor Devices''	60,662, file , and furt	ed on February 7, 2003, ent her identified as Attorney l	itled "Metho Docket No. 5	od of Fabricatii 0033-00005	ng Self-Alig	ned	
	U. S. Patent Application Serial No. 10/339,040, filed on January 9, 2003, entitled "Silicon Carbide Semiconductor Devices with a Regrown Contact Layer", and further identified as Attorney Docket No. 50033-00004.									
EXAMINER				DATE CONSIDERED						
		al if citation considered, whether o e copy of this form with next com			ce with MPEP Section 609; Dr	aw line throug	h citation if not i	n conformar	ice and not	